

# 1-MHz, Micro-Power, Low-Noise, RRIO,1.8-V CMOS OPERATIONAL AMPLIFIER **Precision Value Line Series**

Check for Samples: OPA313, OPA2313, OPA4313

#### **FEATURES**

Low I<sub>Q</sub>: 50 µA/ch

Wide Supply Range: 1.8 V to 5.5 V Low Noise: 25 nV/\(\sqrt{Hz}\) at 1 kHz

Gain Bandwidth: 1 MHz

Low Input Bias Current: 0.2 pA Low Offset Voltage: 0.5 mV

**Unity-Gain Stable** 

Internal RF/EMI Filter

**Extended Temperature Range:** -40°C to +125°C

### **APPLICATIONS**

- **Battery-Powered Instruments:** 
  - Consumer, Industrial, Medical
  - Notebooks, Portable Media Players
- **Sensor Signal Conditioning:** 
  - Loop-Powered
  - Notebooks, Portable Media Players
- **Wireless Sensors:** 
  - Home Security
  - Remote Sensing
  - Wireless Metering

#### DESCRIPTION

The OPA313 family of single-, dual-, and quadchannel op amps represents a new generation of lowcost, general purpose, micro-power operational amplifiers. Featuring rail-to-rail input and output swings, and low quiescent current (50 µA, typ) combined with a wide bandwidth of 1 MHz and very low noise (25 nV/√Hz at 1 kHz) makes this family very attractive for a variety of battery-powered applications that require a good balance between cost and performance. The low input bias current supports those op amps to be used in applications with megaohm source impedances.

The robust design of the OPA313 devices provides ease-of-use to the circuit designer: unity-gain stability with capacitive loads of up to 150 pF, integrated RF/EMI rejection filter, no phase reversal in overdrive conditions, and high electrostatic discharge (ESD) protection (4-kV HBM).

These devices are optimized for operation at voltages as low as  $+1.8 \text{ V} (\pm 0.9 \text{ V})$  and up to  $+5.5 \text{ V} (\pm 2.75 \text{ V})$ , and are specified over the extended temperature range of -40°C to +125°C.

The OPA313 (single) is available in both SC70-5 and SOT23-5 packages. The OPA2313 (dual) is offered in SO-8, MSOP-8, and DFN-8 packages. The quadchannel OPA4313 is offered in a TSSOP-14 package.

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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## PACKAGE INFORMATION(1)

PRODUCT	PACKAGE-LEAD	PACKAGE DESIGNATOR	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING
OPA313	SC70-5	DCK	-40°C to +125°C	SIE
UPASTS	SOT23-5	DBV	-40°C to +125°C	SIF
	SO-8	D	-40°C to +125°C	OP2313
OPA2313	MSOP-8	DGK	-40°C to +125°C	OUSS
	DFN-8	DRG	-40°C to +125°C	SDY
OPA4313	TSSOP-14	PW	-40°C to +125°C	OPA4313

<sup>(1)</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this document, or visit the device product folder at <a href="https://www.ti.com">www.ti.com</a>.

## **ABSOLUTE MAXIMUM RATINGS**(1)

Over operating free-air temperature range, unless otherwise noted.

		OPA313, OPA2313, OPA4313	UNIT
Supply voltage		7	V
0: 1: // : 1	Voltage <sup>(2)</sup>	(V–) – 0.5 to (V+) + 0.5	V
Signal input terminals	Current <sup>(2)</sup>	±10	mA
Output short-circuit (3)		Continuous	mA
Operating temperature, T <sub>A</sub>		-40 to +150	°C
Storage temperature, T <sub>stg</sub>		-65 to +150	°C
Junction temperature, T <sub>J</sub>		+150	°C
	Human body model (HBM)	4000	V
ESD rating	Charged device model (CDM)	1000	V
	Machine model (MM)	200	V

<sup>(1)</sup> Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not supported.

<sup>(2)</sup> Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5 V beyond the supply rails should be current limited to 10 mA or less.

<sup>(3)</sup> Short-circuit to ground, one amplifier per package.



## **ELECTRICAL CHARACTERISTICS: +5.5 V<sup>(1)</sup>**

At T<sub>A</sub> = +25 °C, R<sub>L</sub> = 10 k $\Omega$  connected to V<sub>S</sub> / 2, and V<sub>CM</sub> = V<sub>OUT</sub> = V<sub>S</sub> / 2, unless otherwise noted.

			OPA313, O	OPA313, OPA2313, OPA4313			
PARAMETER OFFSET VOLTAGE		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
OFFSET \	/OLTAGE						
Vos	Input offset voltage			0.5	2.5	mV	
dV <sub>OS</sub> /dT	vs Temperature	$T_A = -40$ °C to +125°C		2		μV/°C	
PSRR	vs power supply	$T_A = -40$ °C to +125°C	74	90		dB	
	Channel separation, dc	At dc		10		μV/V	
INPUT VO	LTAGE RANGE						
V <sub>CM</sub>	Common-mode voltage range	No phase reversal, rail-to-rail input	(V-) - 0.2		(V+) + 0.2	V	
CMRR	Common-mode rejection ratio	$T_A = -40$ °C to +125°C, $(V_S-) - 0.2 \text{ V} < V_{CM} < (V_S+) - 1.3 \text{ V}$	70	85		dB	
CIVIRR	Common-mode rejection ratio	$T_A = -40$ °C to +125°C, $V_{CM} = -0.2$ V to 5.7 V	64	80		dB	
INPUT BI	AS CURRENT				<u>.</u>		
				±0.2	±10	pА	
I <sub>B</sub>	Input bias current	$T_A = -40$ °C to +85°C <sup>(2)</sup>			±50	pА	
		$T_A = -40$ °C to +125°C <sup>(2)</sup>			±600	pA	
				±0.2	±10	pA	
Ios	Input offset current	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}^{(2)}$			±50	pA	
		$T_A = -40$ °C to +125°C <sup>(2)</sup>			±600	pA	
NOISE							
	Input voltage noise (peak-to- peak)	f = 0.1 Hz to 10 Hz		6		$\mu V_{PP}$	
		f = 10 kHz		22		nV/√ <del>Hz</del>	
e <sub>n</sub>	Input voltage noise density	f = 1 kHz		25		nV/√ <del>Hz</del>	
i <sub>n</sub>	Input current noise density	f = 1 kHz		5		fA/√Hz	
INPUT CA	PACITANCE						
<u></u>	Differential			1		pF	
C <sub>IN</sub>	Common-mode			5		pF	
OPEN-LO	OP GAIN						
		$0.05 \text{ V} < \text{V}_{\text{O}} < (\text{V+}) - 0.05 \text{ V}, \text{ R}_{\text{L}} = 100 \text{ k}\Omega$	90	104		dB	
A <sub>OL</sub>	Open-loop voltage gain	$T_A = -40$ °C to +125°C, 0.1 V < $V_O$ < (V+) - 0.1 V	104	116		dB	
		$0.3 \text{ V} < \text{V}_{\text{O}} < (\text{V+}) - 0.3 \text{ V}, \text{ R}_{\text{L}} = 2 \text{ k}\Omega$	100	110		dB	
	Phase margin	V <sub>S</sub> = 5.0 V, G = +1		65		degrees	

<sup>(1)</sup> Parameters with minimum or maximum specification limits are 100% production tested at +25°C, unless otherwise noted. Over temperature limits are based on characterization and statistical analysis.

<sup>(2)</sup> Specified by design and characterization; not production tested.



# ELECTRICAL CHARACTERISTICS: +5.5 V<sup>(1)</sup> (continued)

At T<sub>A</sub> = +25 °C, R<sub>L</sub> = 10 k $\Omega$  connected to V<sub>S</sub> / 2, and V<sub>CM</sub> = V<sub>OUT</sub> = V<sub>S</sub> / 2, unless otherwise noted.

			OPA313, OPA2	313, OF	PA4313	
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
FREQUE	NCY RESPONSE				,	
GBW	Gain-bandwidth product	V <sub>S</sub> = 5.0 V, C <sub>L</sub> = 10 pF		1		MHz
SR	Slew rate	V <sub>S</sub> = 5.0 V, G = +1		0.5		V/µs
	Carrier a disease	To 0.1%, V <sub>S</sub> = 5.0 V, 2-V step , G = +1		5 6 3		μs
t <sub>S</sub>	Settling time	To 0.01%, $V_S = 5.0 \text{ V}$ , 2-V step , $G = +1$		6		μs
	Overload recovery time	$V_S = 5.0 \text{ V}, V_{IN} \times \text{Gain} > V_S$		3		μs
THD+N	Total harmonic distortion + noise (3)	V <sub>S</sub> = 5.0 V, V <sub>O</sub> = 1 V <sub>RMS</sub> , G = +1, f = 1 kHz	0.00	)45%		
OUTPUT						
		$R_{L} = 100 \text{ k}\Omega^{(4)}$		5	20	mV
	Voltage output swing from supply	$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}, R_L = 100 \text{ k}\Omega^{(4)}$		30 75 100	30	mV
$V_{O}$	rails	$R_L = 2 k\Omega^{(4)}$		75	100	mV
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}, \ R_L = 2 \text{ k}\Omega$				mV
	Oh ant aircraft arrange			±15		mA
I <sub>SC</sub>	Short-circuit current	$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$		±12		mA
Ro	Open-loop output impedance			2300		Ω
POWER S	SUPPLY					
Vs	Specified voltage range		1.8 (±0.9)	į	5.5 (±2.75)	V
	Outcome autront nor amplifica	$I_{O} = 0 \text{ mA}, V_{S} = 5.0 \text{ V}$		50	60	μΑ
IQ	Quiescent current per amplifier	$T_A = -40$ °C to +125°C, $V_S = 5.0$ V, $I_O = 0$ mA			85	μΑ
	Power-on time	$V_S = 0 \text{ V to 5 V, to 90\% I}_Q \text{ level}$		10		μs
TEMPERA	ATURE					
	Specified range		-40		+125	°C
	Operating range		-40		+150	°C
	Storage range		-65		+150	°C

<sup>(3)</sup> Third-order filter; bandwidth = 80 kHz at −3 dB.

<sup>(4)</sup> Specified by design and characterization; not production tested.



## **ELECTRICAL CHARACTERISTICS: +1.8 V<sup>(1)</sup>**

At  $T_A$  = +25 °C,  $R_L$  = 10 k $\Omega$  connected to  $V_S$  / 2,  $V_{CM}$  =  $V_{S+}$  – 1.3 V, and  $V_{OUT}$  =  $V_S$  / 2, unless otherwise noted.

			OPA313, O	PA2313, C	PA4313	
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFFSET '	VOLTAGE					
Vos	Input offset voltage			0.5	2.5	mV
dV <sub>OS</sub> /dT	vs Temperature	$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$		2		μV/°C
PSRR	vs power supply	$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	74	90		dB
	Channel separation, dc	At dc		10		μV/V
INPUT VO	DLTAGE RANGE					
V <sub>CM</sub>	Common-mode voltage range	No phase reversal, rail-to-rail input	(V-) - 0.2		(V+) + 0.2	V
		$T_A = -40$ °C to +125°C, $(V_S-) - 0.2 \text{ V} < V_{CM} < (V_S+) - 1.3 \text{ V}$	70	85		dB
CMRR	Common-mode rejection ratio	$V_S = 1.8 \text{ V}, V_{CM} = -0.2 \text{ V to } +1.8 \text{ V}$	58	73	MAX  5 2.5  2 0  0 0  (V+) + 0.2  5 3  0 ±600  2 ±10  ±50  ±600  6 2  5 5  1 5  0 0	
		$T_A = -40$ °C to +125°C, $V_{CM} = -0.2$ V to 1.6 V	58	70		dB
INPUT BI	AS CURRENT		,		•	
				±0.2	±10	pА
$I_B$	Input bias current	$T_A = -40$ °C to +85°C <sup>(2)</sup>			±50	pА
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}^{(2)}$			±600	pА
				±0.2	±10	pА
Ios	Input offset current	$T_A = -40$ °C to +85°C <sup>(2)</sup>			±50	pА
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}^{(2)}$			±600	pА
NOISE			<del> </del>			
	Input voltage noise (peak-to- peak)	f = 0.1 Hz to 10 Hz		6		$\mu V_{PP}$
_	lander of the management of the state of	f = 10 kHz		22		nV/√ <del>Hz</del>
e <sub>n</sub>	Input voltage noise density	f = 1 kHz		25		nV/√ <del>Hz</del>
i <sub>n</sub>	Input current noise density	f = 1 kHz		5		fA/√Hz
INPUT CA	APACITANCE				•	
0	Differential			1		pF
C <sub>IN</sub>	Common-mode			5		pF
OPEN-LO	OOP GAIN	·	·		"	
	0 1 1 1	$T_A = -40$ °C to +125°C, 0.1 V < $V_O$ < (V+) - 0.1 V	90	110		dB
A <sub>OL</sub>	Open-loop voltage gain	$0.05 \text{ V} < \text{V}_{\text{O}} < (\text{V+}) - 0.05 \text{ V}, R_{\text{L}} = 100 \text{ k}\Omega$	100	110		dB

<sup>(1)</sup> Parameters with minimum or maximum specification limits are 100% production tested at +25°C, unless otherwise noted. Over temperature limits are based on characterization and statistical analysis.

<sup>(2)</sup> Specified by design and characterization; not production tested.



# **ELECTRICAL CHARACTERISTICS:** +1.8 V<sup>(1)</sup> (continued)

At  $T_A = +25$  °C,  $R_L = 10$  k $\Omega$  connected to  $V_S$  / 2,  $V_{CM} = V_{S+} - 1.3$  V, and  $V_{OUT} = V_S$  / 2, unless otherwise noted.

			OPA313, OPA	2313, OF	PA4313	
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
FREQUE	NCY RESPONSE		'		•	
GBW	Gain-bandwidth product	C <sub>L</sub> = 10 pF		0.9		MHz
SR	Slew rate	G = +1		0.45		V/µs
FREQUENCE GBW SR  ts  THD+N  OUTPUT  Vo  Isc Ro POWER SL Vs Iq	0.00	To 0.1%, $V_S = 5.0 \text{ V}$ , 2-V step , $G = +1$		5		μs
	Settling time	To 0.01%, V <sub>S</sub> = 5.0 V, 2-V step , G = +1		6		μs
	Overload recovery time	$V_S = 5.0 \text{ V}, V_{IN} \times \text{Gain} > V_S$		3		μs
THD+N	Total harmonic distortion + noise (3)	V <sub>S</sub> = 5.0 V, V <sub>O</sub> = 1 V <sub>RMS</sub> , G = +1, f = 1 kHz	0.0	0045%		
OUTPUT						
		$R_L = 100 \text{ k}\Omega^{(4)}$		5	15	mV
OUTPUT Vo Isc Ro	Voltage output swing from supply	$T_A = -40$ °C to +125°C, $R_L = 100 \text{ k}\Omega^{(4)}$			30	mV
	rails	$R_L = 2 k\Omega^{(4)}$		25	50	mV
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}, R_L = 2 \text{ k}\Omega$			125	mV
I <sub>SC</sub>	Short-circuit current			±6		mA
Ro	Open-loop output impedance			2300		Ω
POWER S	SUPPLY					
Vs	Specified voltage range		1.8 (±0.9)		5.5 (±2.75)	V
IQ	Quiescent current per amplifier	$I_O = 0 \text{ mA}$		50	60	μA
	Power-on time	V <sub>S</sub> = 0 V to 5 V, to 90% I <sub>Q</sub> level		10		μs
TEMPERA	ATURE					
	Specified range		-40		+125	°C
	Operating range		-40		+150	°C
	Storage range		-65		+150	°C

<sup>(3)</sup> Third-order filter; bandwidth = 80 kHz at -3 dB.

<sup>(4)</sup> Specified by design and characterization; not production tested.



#### **THERMAL INFORMATION: OPA313**

		OPA		
	THERMAL METRIC <sup>(1)</sup>	DBV (SOT23)	DCK (SC70)	UNITS
		5 PINS	5 PINS	
$\theta_{JA}$	Junction-to-ambient thermal resistance	228.5	281.4	
$\theta_{JC(top)}$	Junction-to-case(top) thermal resistance	99.1	91.6	
$\theta_{JB}$	Junction-to-board thermal resistance	54.6	59.6	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	7.7	1.5	*C/VV
ΨЈВ	Junction-to-board characterization parameter	53.8	58.8	
$\theta_{JC(bottom)}$	Junction-to-case(bottom) thermal resistance	N/A	N/A	

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

### **THERMAL INFORMATION: OPA2313**

			OPA2313		
	THERMAL METRIC <sup>(1)</sup>	D (SO)	DGK (MSOP)	DRG (DFN)	UNITS
		8 PINS	8 PINS	8 PINS	
$\theta_{JA}$	Junction-to-ambient thermal resistance	138.4	191.2	53.8	
$\theta_{JC(top)}$	Junction-to-case(top) thermal resistance	89.5	61.9	69.2	
$\theta_{JB}$	Junction-to-board thermal resistance	78.6	111.9	20.1	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	29.9	5.1	3.8	- °C/W
ΨЈВ	Junction-to-board characterization parameter	78.1	110.2	20.0	
$\theta_{JC(bottom)}$	Junction-to-case(bottom) thermal resistance	N/A	N/A	11.6	

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

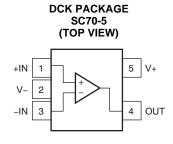
#### **THERMAL INFORMATION: OPA4313**

		OPA4313		
	THERMAL METRIC(1)	PW (TSSOP)	UNITS	
		14 PINS	1	
$\theta_{JA}$	Junction-to-ambient thermal resistance	121.0		
$\theta_{\text{JC(top)}}$	Junction-to-case(top) thermal resistance	49.4		
$\theta_{JB}$	Junction-to-board thermal resistance	62.8	0000	
Ψлτ	Junction-to-top characterization parameter	5.9	°C/W	
ΨЈВ	Junction-to-board characterization parameter	62.2	1	
$\theta_{\text{JC(bottom)}}$	Junction-to-case(bottom) thermal resistance	N/A		

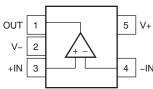
(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.



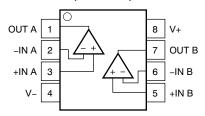
#### **PIN CONFIGURATIONS**



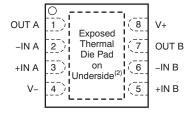




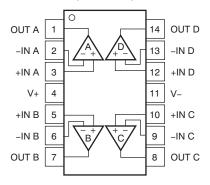
#### D, DGK PACKAGES SO-8, MSOP-8 (TOP VIEW)



#### DRG PACKAGE<sup>(1)</sup> DFN-8 (TOP VIEW)



#### PW PACKAGE TSSOP-14 (TOP VIEW)



- (1) Pitch: 0,65 mm.
- (2) Connect thermal pad to V-. Pad size: 1,8 mm  $\times$  1,5 mm.



### **TYPICAL CHARACTERISTICS**

#### **Table 1. Characteristic Performance Measurements**

TITLE	FIGURE
Open-Loop Gain and Phase vs Frequency	Figure 1
Open-Loop Gain vs Temperature	Figure 2
Quiescent Current vs Supply Voltage	Figure 3
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EMIRR IN+ vs Frequency	Figure 33

### TYPICAL CHARACTERISTICS

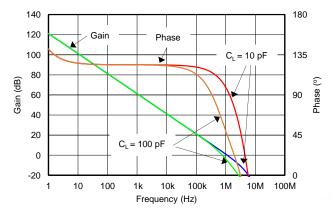


Figure 1. OPEN-LOOP GAIN AND PHASE vs FREQUENCY

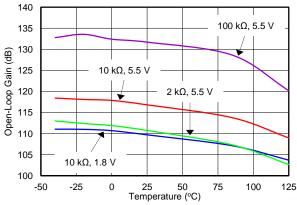


Figure 2. OPEN-LOOP GAIN vs TEMPERATURE

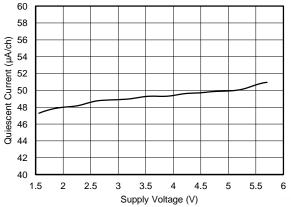


Figure 3. QUIESCENT CURRENT vs SUPPLY

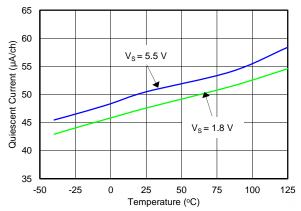


Figure 4. QUIESCENT CURRENT vs TEMPERATURE

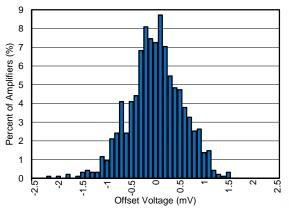


Figure 5. OFFSET VOLTAGE PRODUCTION DISTRIBUTION

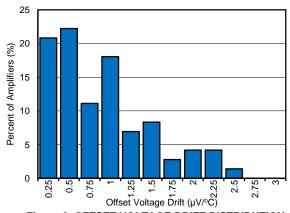


Figure 6. OFFSET VOLTAGE DRIFT DISTRIBUTION



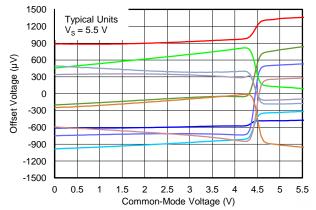


Figure 7. OFFSET VOLTAGE vs COMMON-MODE VOLTAGE

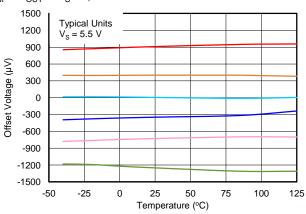


Figure 8. OFFSET VOLTAGE vs TEMPERATURE

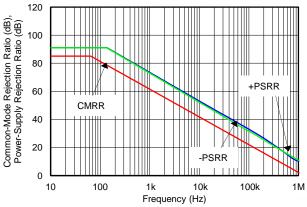


Figure 9. CMRR AND PSRR vs FREQUENCY (Referred-to-Input)

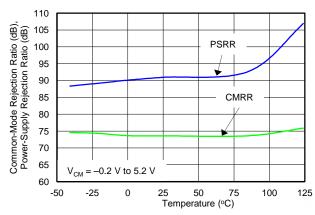


Figure 10. CMRR AND PSRR vs TEMPERATURE

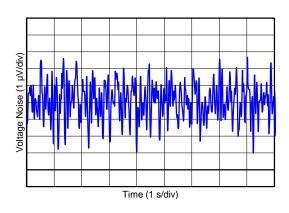


Figure 11. 0.1-Hz TO 10-Hz INPUT VOLTAGE NOISE

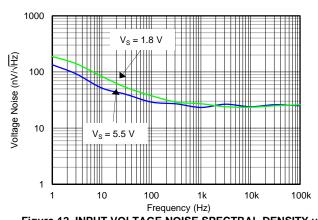


Figure 12. INPUT VOLTAGE NOISE SPECTRAL DENSITY vs FREQUENCY

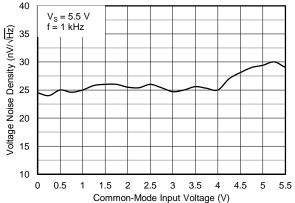


Figure 13. VOLTAGE NOISE vs COMMON-MODE VOLTAGE

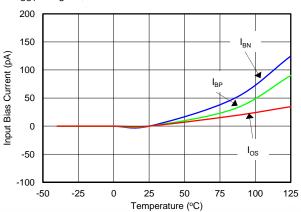


Figure 14. INPUT BIAS AND OFFSET CURRENT vs TEMPERATURE

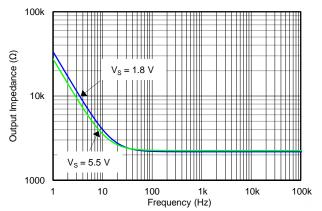


Figure 15. OPEN-LOOP OUTPUT IMPEDANCE vs FREQUENCY

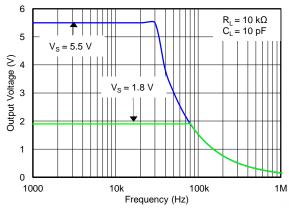


Figure 16. MAXIMUM OUTPUT VOLTAGE vs FREQUENCY AND SUPPLY VOLTAGE

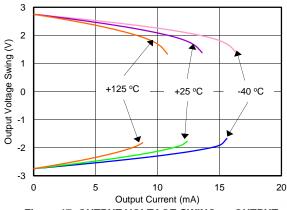


Figure 17. OUTPUT VOLTAGE SWING vs OUTPUT CURRENT (Over Temperature)

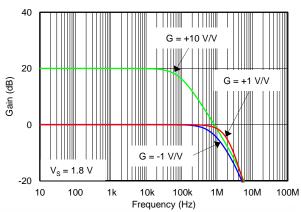


Figure 18. CLOSED-LOOP GAIN vs FREQUENCY (Minimum Supply)



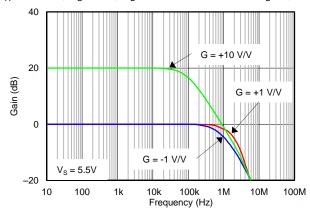
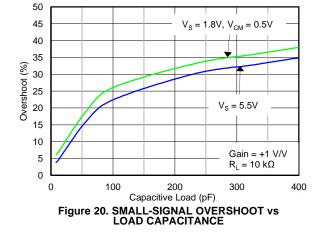


Figure 19. CLOSED-LOOP GAIN vs FREQUENCY (Maximum Supply)



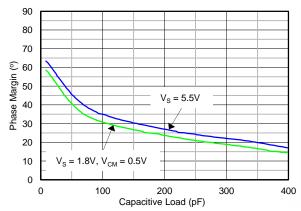


Figure 21. PHASE MARGIN vs CAPACITIVE LOAD

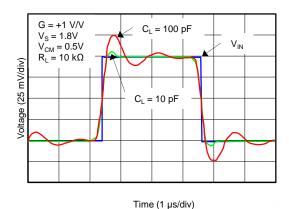


Figure 22. SMALL-SIGNAL PULSE RESPONSE (Minimum Supply)

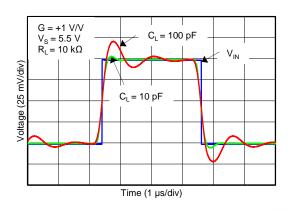


Figure 23. SMALL-SIGNAL PULSE RESPONSE (Maximum Supply)

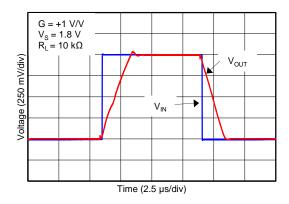


Figure 24. LARGE-SIGNAL PULSE RESPONSE (Minimum Supply)

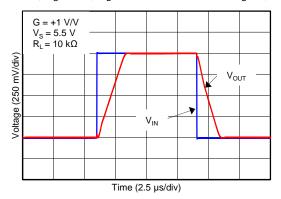


Figure 25. LARGE-SIGNAL PULSE RESPONSE (Maximum Supply)

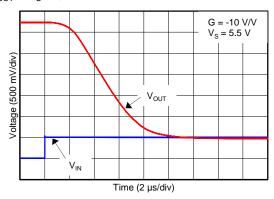


Figure 26. POSITIVE OVERLOAD RECOVERY

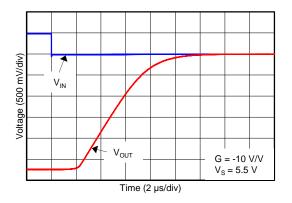


Figure 27. NEGATIVE OVERLOAD RECOVERY

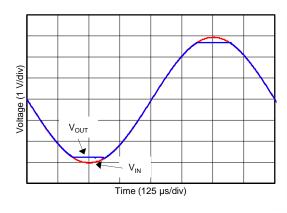


Figure 28. NO PHASE REVERSAL

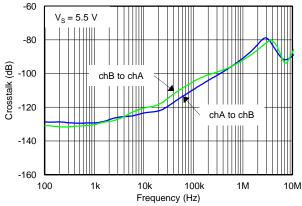


Figure 29. CHANNEL SEPARATION vs FREQUENCY

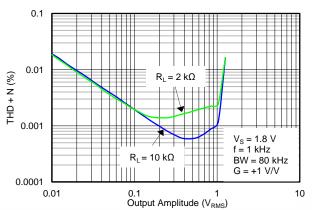


Figure 30. THD+N vs OUTPUT AMPLITUDE (Minimum Supply)



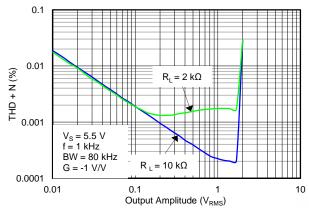


Figure 31. THD+N vs OUTPUT AMPLITUDE (Maximum Supply)

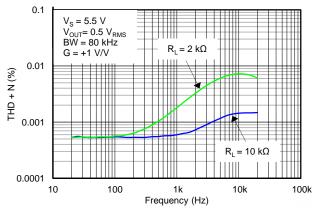


Figure 32. THD+N vs FREQUENCY

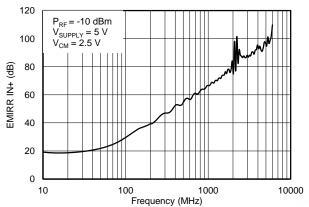


Figure 33. EMIRR IN+ vs FREQUENCY



#### APPLICATION INFORMATION

The OPA313 is a family of low-power, rail-to-rail input and output operational amplifiers specifically designed for portable applications. These devices operate from 1.8 V to 5.5 V, are unity-gain stable, and suitable for a wide range of general-purpose applications. The class AB output stage is capable of driving  $\leq$  10-k $\Omega$  loads connected to any point between V+ and ground. The input common-mode voltage range includes both rails, and allows the OPA313 family to be used in virtually any single-supply application. Rail-to-rail input and output swing significantly increases dynamic range, especially in low-supply applications, and makes them ideal for driving sampling analog-to-digital converters (ADCs).

The OPA313 features 1-MHz bandwidth and 0.5-V/ $\mu$ s slew rate with only 50- $\mu$ A supply current per channel, providing good ac performance at very low power consumption. DC applications are also well served with a low input noise voltage of 25 nV/ $\sqrt{Hz}$  at 1 kHz, low input bias current (0.2 pA), and an input offset voltage of 0.5 mV (typical). The typical offset voltage drift is 2  $\mu$ V/°C; over the full temperature range the input offset voltage changes only 200  $\mu$ V (0.5 mV to 0.7 mV).

#### **OPERATING VOLTAGE**

The OPA313 series op amps are fully specified and ensured for operation from +1.8 V to +5.5 V. In addition, many specifications apply from  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ . Parameters that vary significantly with operating voltages or temperature are shown in the Typical Characteristics graphs. Power-supply pins should be bypassed with 0.01- $\mu\text{F}$  ceramic capacitors.

#### **RAIL-TO-RAIL INPUT**

The input common-mode voltage range of the OPA313 series extends 200 mV beyond the supply rails. This performance is achieved with a complementary input stage: an N-channel input differential pair in parallel with a P-channel differential pair, as shown in Figure 34. The N-channel pair is active for input voltages close to the positive rail, typically (V+) - 1.3 V to 200 mV above the positive supply, while the P-channel pair is on for inputs from 200 mV below the negative supply to approximately (V+) - 1.3 V. There is a small transition region, typically (V+) - 1.4 V to (V+) - 1.2 V, in which both pairs are on. This 200-mV transition region can vary up to 300 mV with process variation. Thus, the transition region (both stages on) can range from (V+) - 1.7 V to (V+) - 1.5 V on the low end, up to (V+) - 1.1 V to (V+) - 0.9 V on the high end. Within this transition region, PSRR, CMRR, offset voltage, offset drift, and THD may be degraded compared to device operation outside this region.

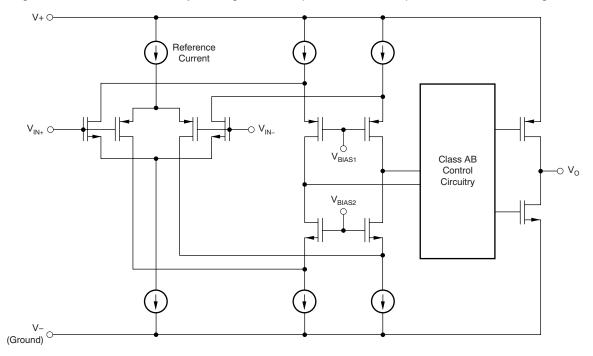


Figure 34. Simplified Schematic



#### INPUT AND ESD PROTECTION

The OPA313 family incorporates internal electrostatic discharge (ESD) protection circuits on all pins. In the case of input and output pins, this protection primarily consists of current-steering diodes connected between the input and power-supply pins. These ESD protection diodes also provide in-circuit, input overdrive protection, as long as the current is limited to 10 mA as stated in the Absolute Maximum Ratings. Figure 35 shows how a series input resistor may be added to the driven input to limit the input current. The added resistor contributes thermal noise at the amplifier input and its value should be kept to a minimum in noise-sensitive applications.

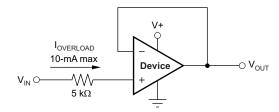


Figure 35. Input Current Protection

### **COMMON-MODE REJECTION RATIO (CMRR)**

CMRR for the OPA313 is specified in several ways so the best match for a given application may be used; see the Electrical Characteristics. First, the CMRR of the device in the common-mode range below the transition region  $[V_{CM} < (V+) - 1.3 \text{ V}]$  is given. This specification is the best indicator of the capability of the device when the application requires use of one of the differential input pairs. Second, the CMRR over the entire common-mode range is specified at  $(V_{CM} = -0.2 \text{ V} \text{ to } 5.7 \text{ V})$ . This last value includes the variations seen through the transition region (see Figure 7).

#### **EMI SUSCEPTIBILITY AND INPUT FILTERING**

Operational amplifiers vary with regard to the susceptibility of the device to electromagnetic interference (EMI). If conducted EMI enters the op amp, the dc offset observed at the amplifier output may shift from its nominal value while EMI is present. This shift is a result of signal rectification associated with the internal semiconductor junctions. While all op amp pin functions can be affected by EMI, the signal input pins are likely to be the most susceptible. The OPA313 operational amplifier family incorporate an internal input low-pass filter that reduces the amplifiers response to EMI. Both common-mode and differential mode filtering are provided by this filter. The filter is designed for a cutoff frequency of approximately 35 MHz (–3 dB), with a roll-off of 20 dB per decade.

Texas Instruments has developed the ability to accurately measure and quantify the immunity of an operational amplifier over a broad frequency spectrum extending from 10 MHz to 6 GHz. The EMI rejection ratio (EMIRR) metric allows op amps to be directly compared by the EMI immunity. Figure 33 illustrates the results of this testing on the OPA313 family. Detailed information can also be found in the application report, *EMI Rejection Ratio of Operational Amplifiers* (SBOA128), available for download from www.ti.com.

#### **RAIL-TO-RAIL OUTPUT**

Designed as a micro-power, low-noise operational amplifier, the OPA313 delivers a robust output drive capability. A class AB output stage with common-source transistors is used to achieve full rail-to-rail output swing capability. For resistive loads up to 10 k $\Omega$ , the output swings typically to within 5 mV of either supply rail regardless of the power-supply voltage applied. Different load conditions change the ability of the amplifier to swing close to the rails; refer to the typical characteristic graph, *Output Voltage Swing vs Output Current*.

#### CAPACITIVE LOAD AND STABILITY

The OPA313 is designed to be used in applications where driving a capacitive load is required. As with all op amps, there may be specific instances where the OPA313 can become unstable. The particular op amp circuit configuration, layout, gain, and output loading are some of the factors to consider when establishing whether or not an amplifier is stable in operation. An op amp in the unity-gain (+1-V/V) buffer configuration that drives a capacitive load exhibits a greater tendency to be unstable than an amplifier operated at a higher noise gain. The capacitive load, in conjunction with the op amp output resistance, creates a pole within the feedback loop that degrades the phase margin. The degradation of the phase margin increases as the capacitive loading increases. When operating in the unity-gain configuration, the OPA313 remains stable with a pure capacitive load up to approximately 1 nF. The equivalent series resistance (ESR) of some very large capacitors ( $C_L$  greater than 1  $\mu$ F) is sufficient to alter the phase characteristics in the feedback loop such that the amplifier remains stable. Increasing the amplifier closed-loop gain allows the amplifier to drive increasingly larger capacitance. This increased capability is evident when observing the overshoot response of the amplifier at higher voltage gains. See the typical characteristic graph, *Small-Signal Overshoot vs. Capacitive Load*.

One technique for increasing the capacitive load drive capability of the amplifier operating in a unity-gain configuration is to insert a small resistor, typically 10  $\Omega$  to 20  $\Omega$ , in series with the output, as shown in Figure 36. This resistor significantly reduces the overshoot and ringing associated with large capacitive loads. One possible problem with this technique, however, is that a voltage divider is created with the added series resistor and any resistor connected in parallel with the capacitive load. The voltage divider introduces a gain error at the output that reduces the output swing.

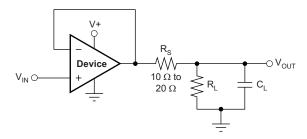


Figure 36. Improving Capacitive Load Drive

#### **DFN PACKAGE**

The OPA2313 (dual version) uses the DFN style package (also known as SON); this package is a QFN with contacts on only two sides of the package bottom. This leadless package maximizes printed circuit board (PCB) space and offers enhanced thermal and electrical characteristics through an exposed pad. One of the primary advantages of the DFN package is its low, 0.9-mm height. DFN packages are physically small, have a smaller routing area, improved thermal performance, reduced electrical parasitics, and use a pinout scheme that is consistent with other commonly-used packages, such as SO and MSOP. Additionally, the absence of external leads eliminates bent-lead issues.

The DFN package can easily be mounted using standard PCB assembly techniques. See Application Note, *QFN/SON PCB Attachment* (SLUA271) and Application Report, *Quad Flatpack No-Lead Logic Packages* (SCBA017), both available for download from www.ti.com.

#### NOTE

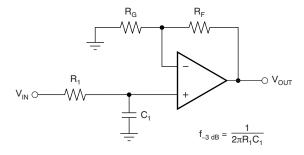
The exposed leadframe die pad on the bottom of the DFN package should be connected to the most negative potential (V–).



#### **APPLICATION EXAMPLES**

#### **GENERAL CONFIGURATIONS**

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to establish this limited bandwidth is to place an RC filter at the noninverting terminal of the amplifier, as Figure 37 shows.



$$\frac{V_{OUT}}{V_{IN}} = \left(1 + \frac{R_F}{R_G}\right) \left(\frac{1}{1 + sR_1C_1}\right)$$

Figure 37. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task, as Figure 38 shows. For best results, the amplifier should have a bandwidth that is eight to 10 times the filter frequency bandwidth. Failure to follow this guideline can result in phase shift of the amplifier.

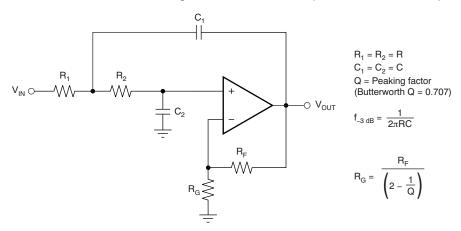


Figure 38. Two-Pole Low-Pass Sallen-Key Filter



### **REVISION HISTORY**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Cł	hanges from Revision B (December 2012) to Revision C	Page
•	Changed first Open-Loop Gain, A <sub>OL</sub> typical specification in Electrical Characteristics: +5.5 V table	3
•	Updated Figure 10	
•	Updated Figure 19 through Figure 22	12
CI	hanges from Revision A (Sepetmber 2012) to Revision B	Page
•	Changed title of document	1
•	Changed third paragraph of Description section	1
•	Changed title of Electrical Characteristics: +5.5 V table	
•	Deleted middle two rows from Input Voltage Range, CMRR parameter in Electrical Characteristics: +5.5 V table	
•	Changed test conditions of Input Voltage Range, CMRR parameter in Electrical Characteristics: +5.5 V table	
•	Added footnote to Input Bias Current, $I_B$ and $I_{OS}$ parameters in Electrical Characteristics: +5.5 V table	3
•	Changed Open-Loop Gain, A <sub>OL</sub> parameter in Electrical Characteristics: +5.5 V table	
•	Deleted first row from Frequency Response, GBW parameter in Electrical Characteristics: +5.5 V table	
•	Deleted first row from Frequency Response, SR parameter in Electrical Characteristics: +5.5 V table	4
•	Changed Output, Vo parameter in Electrical Characteristics: +5.5 V table	4
•	Changed Output, I <sub>SC</sub> parameter in Electrical Characteristics: +5.5 V table	4
•	Changed test conditions for the first row in the Power Supply, $I_Q$ parameter in Electrical Characteristics: +5.5 V table	e 4
•	Changed Electrical Characteristics: +1.8 V table	5
•	Changed conditions of Electrical Characteristics: +1.8 V table	5
•	Changed last row of Input Voltage Range, CMRR parameter in Electrical Characteristics: +1.8 V table	5
•	Changed footnote to Input Bias Current, $I_B$ and $I_{OS}$ parameters in Electrical Characteristics: +1.8 V table	5
•	Changed Open-Loop Gain, A <sub>OL</sub> parameter in Electrical Characteristics: +1.8 V table	5
•	Changed Frequency Response, GBW parameter test conditions in Electrical Characteristics: +1.8 V table	6
•	Changed Frequency Response, SR parameter test conditions in Electrical Characteristics: +1.8 V table	6
•	Changed Output, Vo parameter test conditions in Electrical Characteristics: +1.8 V table	6
•	Changed Output, I <sub>SC</sub> parameter in Electrical Characteristics: +1.8 V table	6
•	Deleted last row from Power Supply, $I_Q$ parameter in Electrical Characteristics: +1.8 V table	6
•	Updated Figure 2	10
CI	hanges from Original (September 2012) to Revision A	Page
•	Changed from product preview to production data	1
_		





6-Feb-2020

#### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
OPA2313ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OP2313	Samples
OPA2313IDGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OUSS	Samples
OPA2313IDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OUSS	Samples
OPA2313IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OP2313	Samples
OPA2313IDRGR	ACTIVE	SON	DRG	8	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SDY	Samples
OPA2313IDRGT	ACTIVE	SON	DRG	8	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SDY	Samples
OPA313IDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SIE	Samples
OPA313IDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SIE	Samples
OPA313IDCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SIF	Samples
OPA313IDCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SIF	Samples
OPA4313IPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4313	Samples
OPA4313IPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4313	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".



## PACKAGE OPTION ADDENDUM

6-Feb-2020

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF OPA2313:

Automotive: OPA2313-Q1

NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

## **PACKAGE MATERIALS INFORMATION**

www.ti.com 24-Apr-2020

## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA2313IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2313IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA2313IDRGR	SON	DRG	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
OPA2313IDRGT	SON	DRG	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
OPA313IDBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
OPA313IDBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
OPA313IDCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
OPA4313IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

www.ti.com 24-Apr-2020



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA2313IDGKR	VSSOP	DGK	8	2500	366.0	364.0	50.0
OPA2313IDR	SOIC	D	8	2500	340.5	338.1	20.6
OPA2313IDRGR	SON	DRG	8	3000	367.0	367.0	35.0
OPA2313IDRGT	SON	DRG	8	250	210.0	185.0	35.0
OPA313IDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
OPA313IDBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
OPA313IDCKR	SC70	DCK	5	3000	180.0	180.0	18.0
OPA4313IPWR	TSSOP	PW	14	2000	367.0	367.0	35.0

# DCK (R-PDSO-G5)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



# DCK (R-PDSO-G5)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.





SMALL OUTLINE TRANSISTOR



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
  3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)



<sup>7.</sup> Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

<sup>8.</sup> Board assembly site may have different recommendations for stencil design.

PW (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
  - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# PW (R-PDSO-G14)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE INTEGRATED CIRCUIT



- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# DGK (S-PDSO-G8)

# PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



# DGK (S-PDSO-G8)

## PLASTIC SMALL OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



# DRG (S-PWSON-N8)

## PLASTIC SMALL OUTLINE NO-LEAD

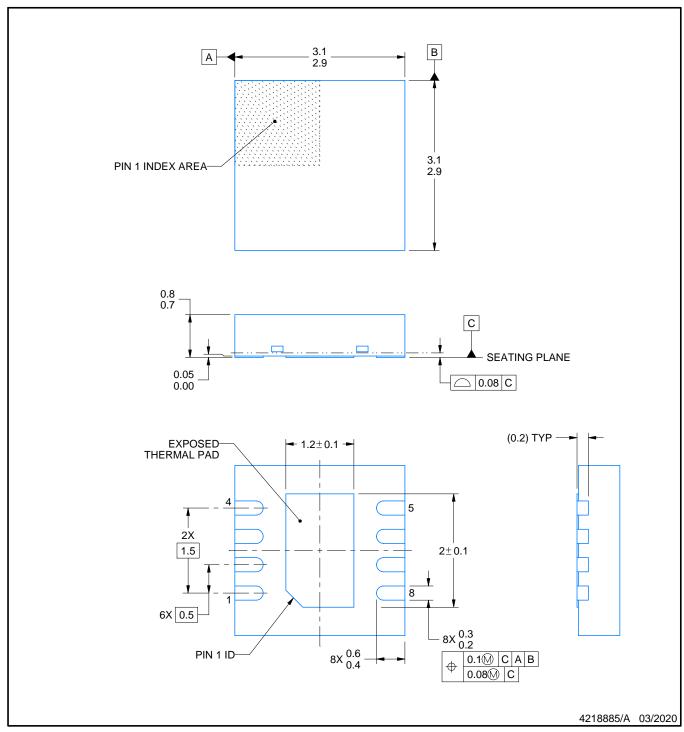


- NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
  - B. This drawing is subject to change without notice.
  - C. SON (Small Outline No-Lead) package configuration.
  - The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
  - E. JEDEC MO-229 package registration pending.





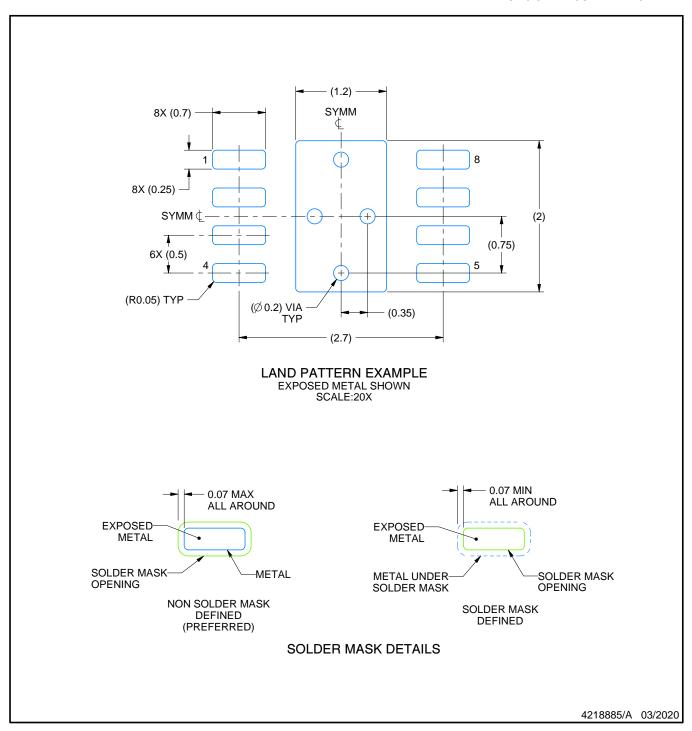
PLASTIC SMALL OUTLINE - NO LEAD



- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
   This drawing is subject to change without notice.
   The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC SMALL OUTLINE - NO LEAD

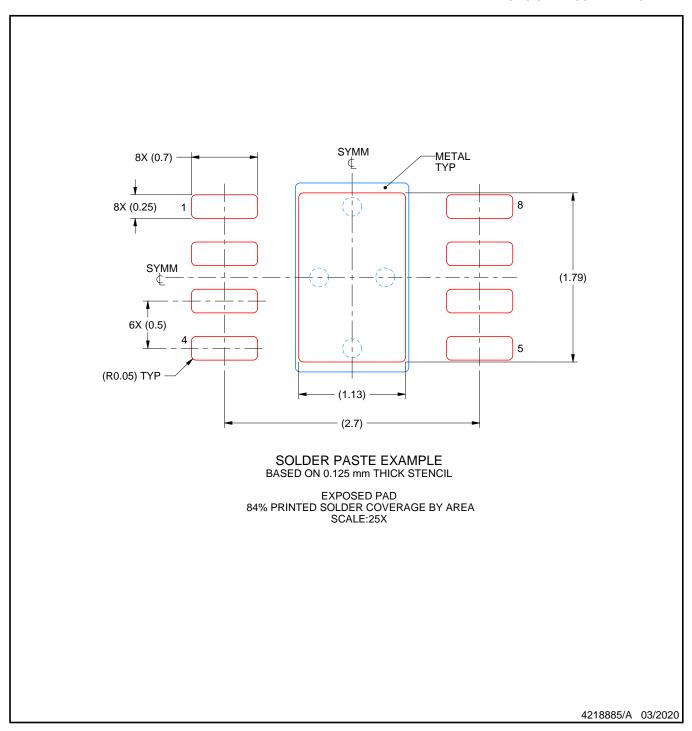


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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